TECHNICAL DATA DATA SHEET 4967, REV. -

# HERMETIC STANDARD RECOVERY RECTIFIER HIGH VOLTAGE

### Features:

- Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- Very High Surge Capacity
- Very suitable for medium frequency applications (upto 3 kHz)
- Soft Reverse Recovery at Low and High Temperature
- Trr guaranteed lower than 10 μsec
- Electrically / Mechanically Stable during and after Packaging

**Maximum Ratings:** 

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	1100	V
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form, T <sub>C</sub> = 65 °C	80	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 msec, sine pulse	720	А
Thermal Impedance	$Z_{TH}$	T <sub>C</sub> = 25 °C	0.5	°C / W
Max. Junction Temperature	TJ	-	- 40 to + 165	°C
Max. Storage Temperature	$T_{stg}$	-	- 55 to + 175	°C

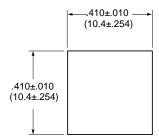
## **Electrical Characteristics:**

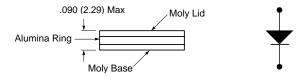
Characteristics	Symbol	Condition	_ Typ	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 20A, Pulse, T <sub>J</sub> = 25 °C	0.88	0.91	V
		@ 80A, Pulse, T <sub>J</sub> = 25 °C	1.20	1.35	
	$V_{F2}$	@ 20A, Pulse, T <sub>J</sub> = 110 °C	-	0.82	V
		@ 80A, Pulse, T <sub>J</sub> = 110 °C	-	1.22	
	I <sub>R1</sub>	$@V_R = 1000V, Pulse, T_J = 25 °C$	4	10	μΑ
Max. Reverse Current		$@V_R = 400V, Pulse, T_J = 25 °C$	1.5	2.5	
	I <sub>R2</sub>	$@V_R = 1000V, Pulse, T_J = 110 °C$	-	250	μΑ
		$@V_R = 400V, Pulse, T_J = 110 °C$	-	50	
Reverse Recovery Time	t <sub>RR</sub>	$I_F = 0.5A$ ; $I_R = 1.0A$ , $I_{RM} = 0.25A$	4	10	μsec
		T <sub>J</sub> = 25 °C			
Max. Junction Capacitance	C⊤	$@V_R = 0V, T_C = 25  ^{\circ}C$	200	-	pF
		$f_{SIG} = 1MHz,$			
		$I_{SIG} = 100 \text{mV (p-p)}$			

## SENSITRON SEMICONDUCTOR

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## **MECHANICAL DIMENSIONS: In Inches / mm**





SHD-3

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